

Small Signal Schottky Diodes

CDBT-70/S/C/A-G

Reverse Voltage: 70 Volts
Forward Current: 70 mA
RoHS Device



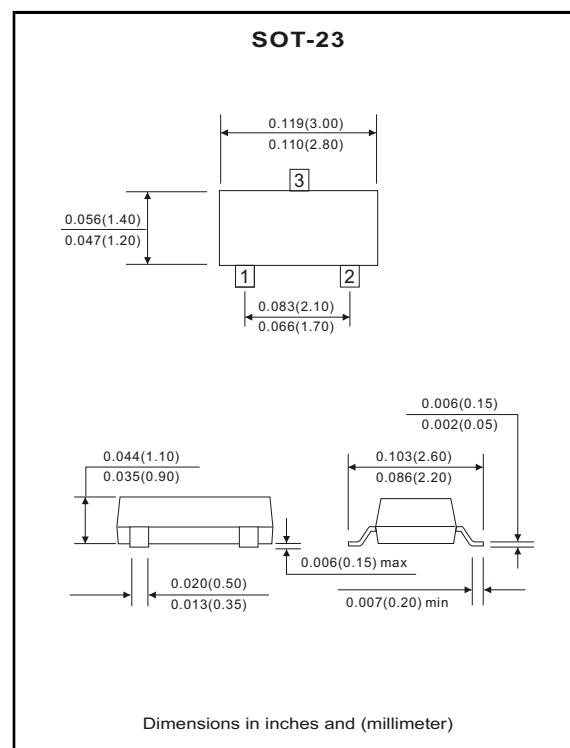
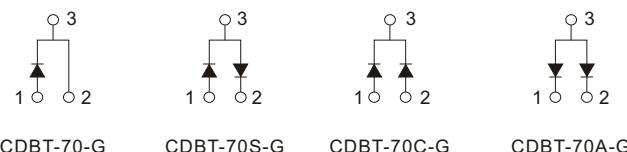
Features

- Design for mounting on small surface.
- High speed switching application, circuit protection.
- Low turn-on voltage.

Mechanical data

- Case: SOT-23, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.008 grams

Circuit diagram



Maximum Ratings and Electrical Characteristics

(at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Value	Units
Repetitive peak reverse voltage	V _{RRM}		70	V
Reverse voltage	V _R		70	V
Forward current	I _F		70	mA
Peak surge forward current	I _{FSM}	T<1.0 sec	0.1	A
Power dissipation	P _D		200	mW
Maximum forward voltage	V _F	@I _F =1.0mA, t _p <300μS @I _F =15mA, t _p <300μS	0.41 1.0	V
Maximum reverse current	I _R	@V _R =50V	0.1	μA
Maximum reverse recovery time	T _{rr}	I _F =I _R =10mA, R _L =100Ω	2	nS
Maximum diode capacitance	C _T	V _R =0V, f=1.0MHz	5	pF
Maximum junction temperature	T _J		125	°C
Storage temperature	T _{STG}		-65 to +150	°C

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COMCHIP
SMD Diodes Specialist

RATING AND CHARACTERISTIC CURVES (CDBT-70/S/C/A-G)

Fig.1 Forward Characteristics

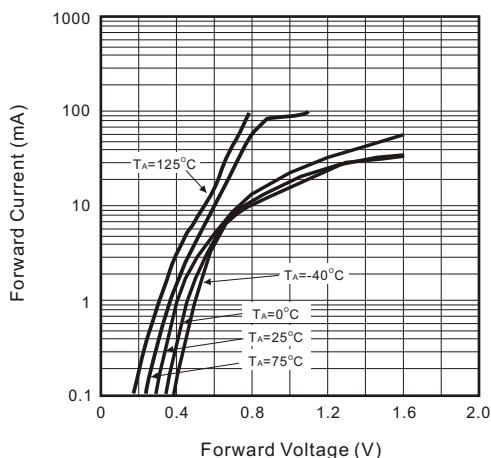


Fig.2 Reverse Characteristics

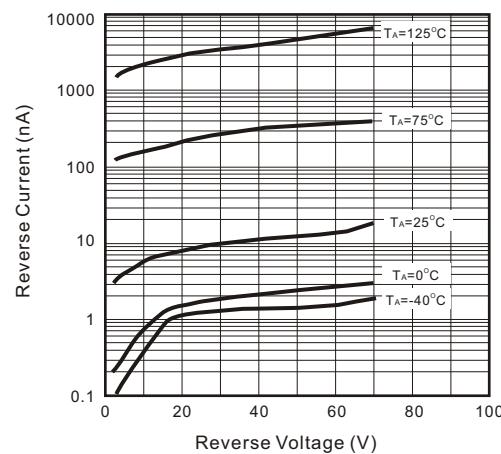


Fig.3 Capacitance Between Terminals Characteristics

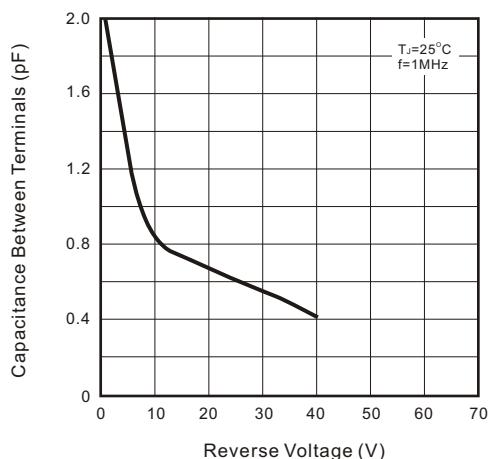


Fig.4 Power Derating Curve

